

Schottky Barrier Rectifier Diode

Features

- Fast Switching
- Low forward voltage drop, V_F
- Guard ring protection
- High surge capacity
- High efficiency, low power loss

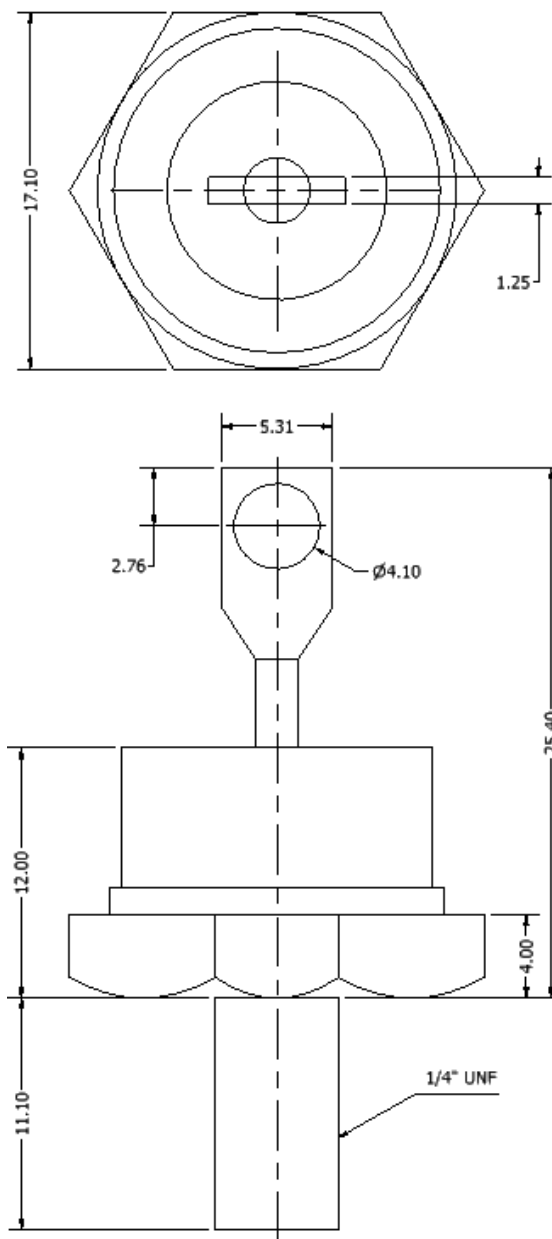
Electrical Ratings ($T_C = 25^\circ\text{C}$, unless otherwise noted)			
Parameter	Symbol	Values	Units
Repetitive peak reverse voltage	V_{RRM}	20	V
DC blocking voltage	V_{DC}		
Non-repetitive peak reverse voltage	V_{RSM}	24	V
Average rectified forward current ($T_C = 85^\circ\text{C}$)	$I_{F(AV)}$	40	A
Non-repetitive peak surge current (surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I_{FSM}	800	A



DO-203AB (DO-5)

Maximum Ratings ($T_C = 25^\circ\text{C}$, unless otherwise noted)				
Parameter	Test Conditions	Symbol	Values	Units
Maximum instantaneous forward voltage	$I_F = 10\text{ A}$	V_F	0.36	V
	$I_F = 40\text{ A}$		0.52	V
	$I_F = 125\text{ A}$		0.98	V
Maximum instantaneous reverse current at rated DC voltage	$T_C = 25^\circ\text{C}$	I_R	20	mA
	$T_C = 100^\circ\text{C}$		150	mA

Thermal & Mechanical Specifications ($T_E = 25^\circ\text{C}$, unless otherwise noted)			
Parameters	Symbol	Values	Units
Maximum thermal resistance, junction to case	$R_{th(jc)}$	1.0	$^\circ\text{C/W}$
Operating junction temperature range	T_J	-65 to +125	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 to +125	$^\circ\text{C}$
Mounting torque (non-lubricated threads)		15	in-lb
Approximate allowable weight	W	45.6	g



ALL DIMENSIONS IN MM